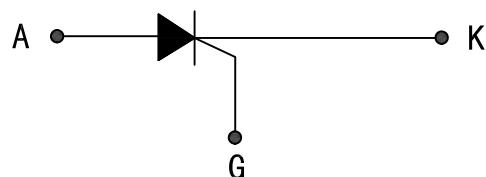
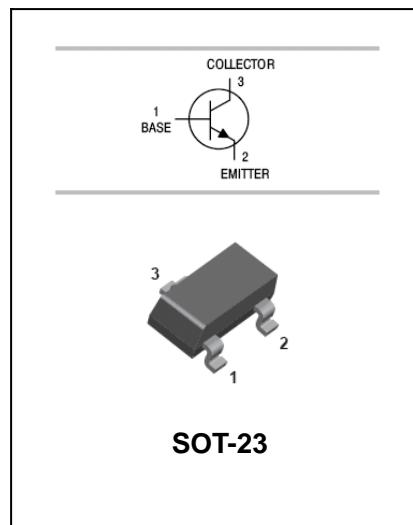


DESCRIPTION:

Highly sensitive triggering levels, the MCR16 Series SCRs is suitable for all applications, where the available gate current is limited, such as capacitive discharge ignitions, motor control in kitchen aids, overvoltage crowbar protection in low power supplies...

MAIN FEATURES

| Symbol | Value | Unit |
|----------------------------------|-------|------|
| I _{T(AV)} | 0.8 | A |
| V _{DRM/V_{RRM}} | 400 | V |
| I _{GT} | ≤200 | μA |



ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Value | Unit |
|--|---------------------|--------------|------------------|
| Storage junction temperature range | T _{stg} | - 40 to +150 | °C |
| Operating junction temperature range | T _j | - 40 to +110 | °C |
| Repetitive Peak Off-state Voltage | V _{DRM} | 400 | V |
| Repetitive Peak Reverse Voltage | V _{RRM} | 400 | V |
| RMS on-state current (180° conduction angle) | I _{T(RMS)} | 0.8 | A |
| Average on-state current (180° conduction angle) | I _{T(AV)} | 0.5 | A |
| Non repetitive surge peak on-state current (T _j =25 °C) | tp=10ms | 9 | A |
| | tp=8.3ms | 10 | A |
| I ² t Value for fusing | I ² t | 0.415 | A ² s |
| Peak gate current tp=20us, T _j =110 °C | I _{GM} | 0.2 | A |
| Average gate power dissipation T _j =110 °C | P _{G(AV)} | 0.1 | W |

ELECTRICAL CHARACTERISTICS($T_j=25^\circ\text{C}$ unless otherwise specified)

| Symbol | Test Condition | MCR16 | | | Unit | |
|-------------------|---|------------------------|------|------|------|------|
| | | Min. | Typ. | Max. | | |
| I _{GT} | V _D =6V R _L =100Ω | - | 40 | 200 | μA | |
| V _{GT} | | - | 0.6 | 0.8 | V | |
| V _{GD} | V _D =V _{DRM} R _L =3.3KΩ R _{GK} =1KΩ T _j =110°C | 0.2 | - | - | V | |
| I _L | I _G =1mA R _{GK} =1KΩ | - | - | 6 | mA | |
| I _H | I _T =50mA R _{GK} =1KΩ | - | - | 5 | mA | |
| V _{TM} | I _T =1A t _p =380μS | T _j =25 °C | - | 1.3 | 1.7 | V |
| dV/dt | V _D =67%V _{DRM} R _{GK} =1KΩ | T _j =110 °C | 10 | - | - | V/μs |
| I _{DRM} | V _D = V _{DRM} R _{GK} =1KΩ | T _j =25 °C | - | - | 5 | μA |
| | | T _j =110 °C | - | - | 0.1 | mA |
| I _{IRRM} | V _R = V _{RRM} R _{GK} =1KΩ | T _j =25 °C | - | - | 5 | μA |
| | | T _j =110 °C | - | - | 0.1 | mA |

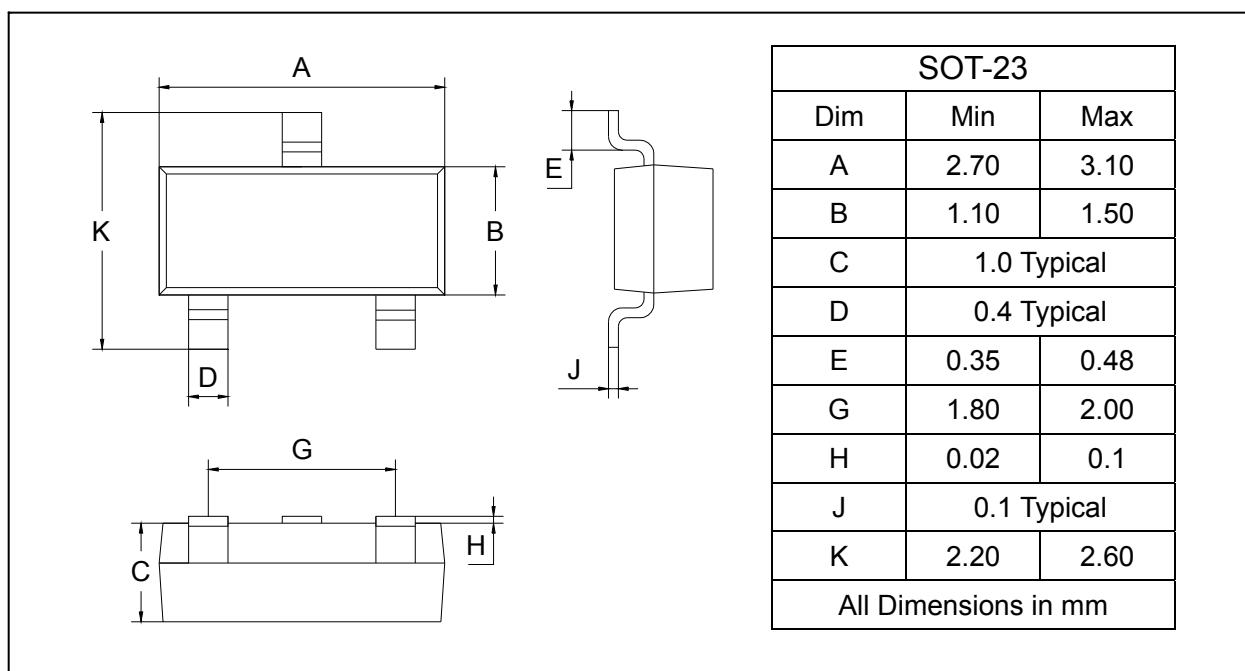
THERMAL RESISTANCES

| Symbol | Parameter | | Value | Unit |
|-----------------------|------------------|--------|-------|------|
| R _{th} (J-C) | Junction to Case | SOT-23 | 75 | °C/W |

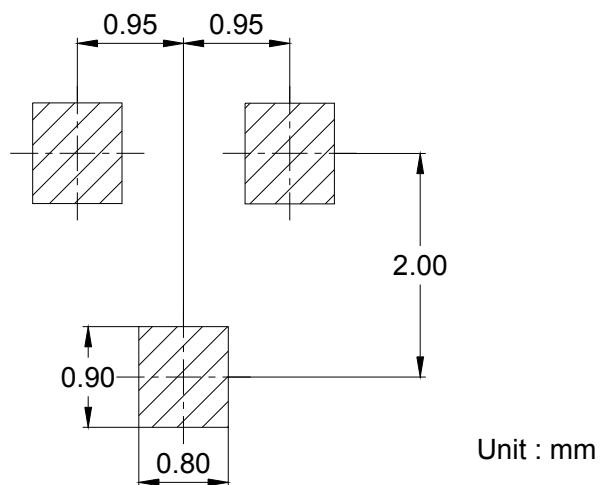
PACKAGE OUTLINE

Plastic surface mounted package

SOT-23



SOLDERING FOOTPRINT



PACKAGE INFORMATION

| Device | Package | Shipping |
|--------|---------|----------------|
| MCR16 | SOT-23 | 3000/Tape&Reel |

FIG.1: Maximum power dissipation versus RMS on-state current(full cycle)

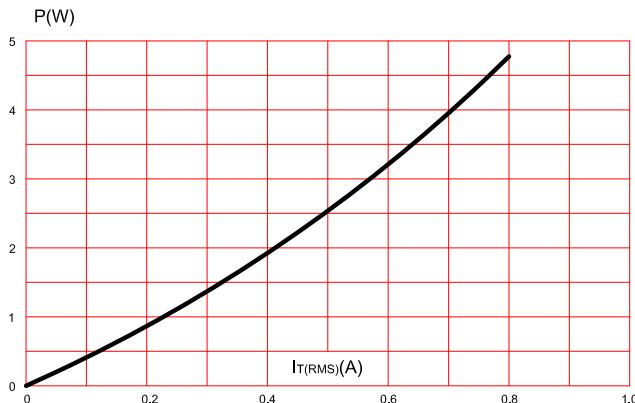


FIG.2: RMS on-state current versus case temperature(full cycle)

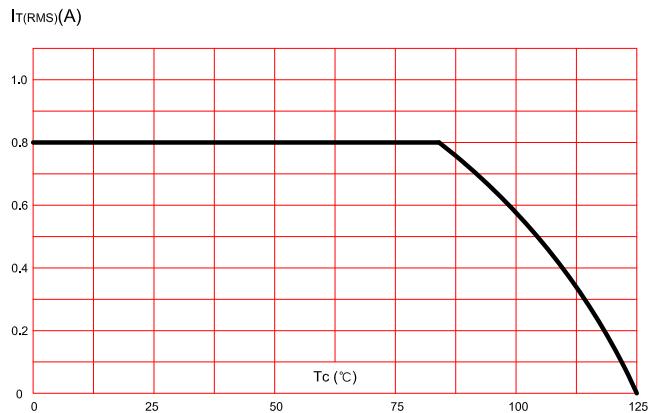


FIG.3: On-state characteristics (maximum values)

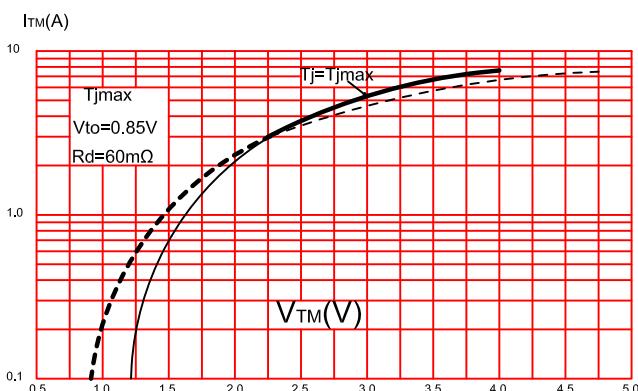


FIG.4: Surge peak on-state current versus number of cycles.

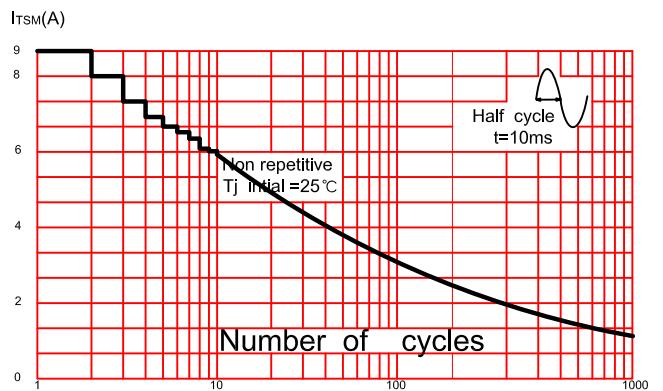


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms.

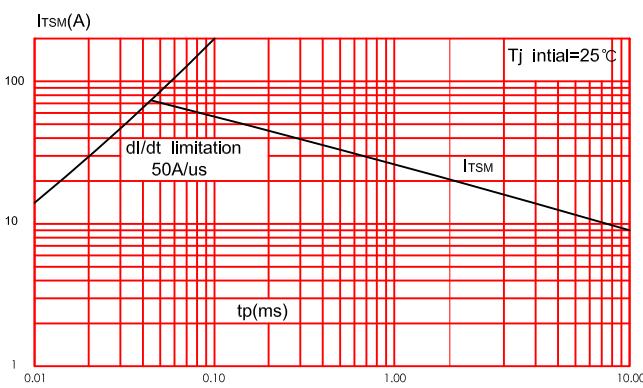


FIG.6: Relative variation of gate trigger current,holding current and latching current versus junction temperature(typical values).

